NLX2G04

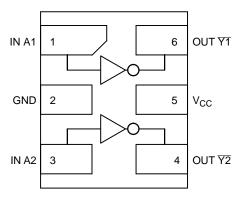
Dual Inverter

The NLX2G04 MiniGate[™] is an advanced high–speed CMOS dual inverter in ultra–small footprint.

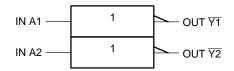
The NLX2G04 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

Features

- High Speed: $t_{PD} = 1.8 \text{ ns} (Typ) @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation: $I_{CC} = 1 \ \mu A$ (Max) at $T_A = 25^{\circ}C$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb–Free Devices









PIN ASSIGNMENT

| 1 | IN A1 |
|---|-----------------|
| 2 | GND |
| 3 | IN A2 |
| 4 | OUT Y2 |
| 5 | V _{CC} |
| 6 | OUT Y1 |

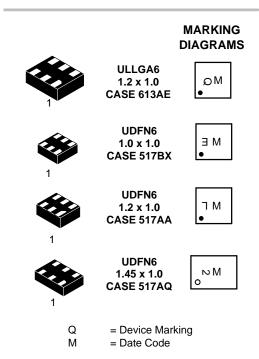
FUNCTION TABLE

| А | Ŷ |
|---|---|
| L | H |
| H | L |



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ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

MAXIMUM RATINGS

| Symbol | Paramet | er | Value | Unit |
|----------------------|--|------------------------|----------------------|------|
| V _{CC} | DC Supply Voltage | | -0.5 to +7.0 | V |
| V _{IN} | DC Input Voltage | | -0.5 to +7.0 | V |
| V _{OUT} | DC Output Voltage | | -0.5 to +7.0 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < GND | -50 | mA |
| Ι _{ΟΚ} | DC Output Diode Current | V _{OUT} < GND | -50 | mA |
| Ι _Ο | DC Output Source/Sink Current | ±50 | mA | |
| I _{CC} | DC Supply Current Per Supply Pin | | ±100 | mA |
| I _{GND} | DC Ground Current per Ground Pin | | ±100 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| ΤL | Lead Temperature, 1 mm from Case for 10 Se | econds | 260 | °C |
| TJ | Junction Temperature Under Bias | 150 | °C | |
| MSL | Moisture Sensitivity | | Level 1 | |
| F _R | Flammability Rating Oxygen | Index: 28 to 34 | UL 94 V–0 @ 0.125 in | |
| I _{LATCHUP} | Latchup Performance Above V_{CC} and Below | GND at 125°C (Note 2) | ±500 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

2. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|------------------|--|-------------|---------------|------|
| V _{CC} | Positive DC Supply Voltage | 1.65 | 5.5 | V |
| V _{IN} | Digital Input Voltage | 0 | 5.5 | V |
| V _{OUT} | Output Voltage | 0 | 5.5 | V |
| T _A | Operating Free–Air Temperature | -55 | +125 | °C |
| Δt/ΔV | Input Transition Rise or Fall Rate $\begin{array}{c} V_{CC}=2.5~V\pm0.2~V\\ V_{CC}=3.3~V\pm0.3~V\\ V_{CC}=5.0~V\pm0.5~V \end{array}$ | 0 0 0 | 20 10 5 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| | | | V _{cc} | ٦ | Γ _A = 25°(| | T _A = +85°C | | T _A = −55°C to +125°C | | |
|---|---|---|---|---|---|---|---|---|---|---|------|
| Symbol | Parameter | Parameter Conditions | (V) | Min | Тур | Max | Min | Max | Min | Max | Unit |
| V _{IH} Low–Level Input Voltage | Input | | 1.65–1.95 | 0.75 x V _{CC} | | | 0.75 x V _{CC} | | 0.75 x V _{CC} | | V |
| | vollage | | 2.3 to 5.5 | 0.70 x V _{CC} | | | 0.70 x V _{CC} | | 0.70 x V _{CC} | | |
| V _{IL} | Low–Level Input Voltage | | 1.65–1.95 | | | 0.25 x V _{CC} | | 0.25 x V _{CC} | | 0.25 x V _{CC} | V |
| | vollage | | 2.3 – 5.5 | | | 0.30 x V _{CC} | | 0.30 x V _{CC} | | 0.30 x V _{CC} | |
| V _{OH} | High– Level Output | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -100 \ \mu A$ | 1.65 – 5.5 | V _{CC} - 0.1 | V _{CC} | | V _{CC} - 0.1 | | V _{CC} - 0.1 | | V |
| | Voltage | $\begin{array}{c} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = -4 \text{ mA} \\ I_{OH} = -8 \text{ mA} \\ I_{OH} = -12 \text{ mA} \\ I_{OH} = -16 \text{ mA} \\ I_{OH} = -24 \text{ mA} \\ I_{OH} = -32 \text{ mA} \end{array}$ | 1.65 2.3 2.7 3.0 3.0 4.5 | 1.29 1.9 2.2 2.4 2.3 3.8 | 1.52 2.1 2.4 2.7 2.5 4.0 | | 1.29 1.9 2.2 2.4 2.3 3.8 | | 1.29 1.9 2.2 2.4 2.3 3.8 | | |
| V _{OL} | Low–Level Output Voltage | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 100 \ \mu A$ | 1.65 – 5.5 | | | 0.1 | | 0.1 | | 0.1 | V |
| | voltage | $\begin{array}{c} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = -4 \text{ mA} \\ I_{OH} = -8 \text{ mA} \\ I_{OH} = -12 \text{ mA} \\ I_{OH} = -16 \text{ mA} \\ I_{OH} = -24 \text{ mA} \\ I_{OH} = -32 \text{ mA} \end{array}$ | 1.65 2.3 2.7 3.0 3.0 4.5 | | 0.08 0.2 0.22 0.28 0.38 0.42 | 0.24 0.3 0.4 0.4 0.55 0.55 | | 0.24 0.3 0.4 0.4 0.55 0.55 | | 0.24 0.3 0.4 0.4 0.55 0.55 | |
| I _{IN} | Input Leakage Current | $0 \le V_{IN} \le 5.5 V$ | 0 to 5.5 | | | ±0.1 | | ±1.0 | | ±1.0 | μΑ |
| I _{OFF} | Power–Off Output Leakage Current | V _{IN} or V _{OUT} = 5.5 V | 0 | | | 1.0 | | 10 | | 10 | μΑ |
| I _{CC} | Quiescent Supply Current | $0 \le V_{IN} \le V_{CC}$ | 5.5 | | | 1.0 | | 10 | | 10 | μΑ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

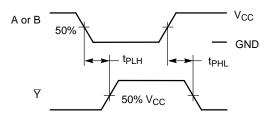
NLX2G04

| | | V _{cc} | cc Test | T _A = 25°C | | | T _A = -55°C to +125°C | | | |
|--|---|-----------------|--|-----------------------|---------|-----|-------------------------------------|-----|------|--|
| Symbol | Parameter | (V) | Condition | Min | Тур | Мах | Min | Max | Unit | |
| t _{PLH} , t _{PHL} | Propagation Delay, Input A to Output \overline{Y} | 1.65 | $R_L = 1 M\Omega,$ $C_L = 15 pF$ | 1.8 | 2.3 | 9.2 | 1.8 | 11 | ns | |
| | | 1.8 | $\begin{array}{l} R_{L} = 1 \ M\Omega, \\ C_{L} = 15 \ pF \end{array}$ | 1.8 | 4.4 | 7.6 | 1.2 | 8.4 | | |
| | | 2.3–2.7 | R _L = 1 MΩ, C _L = 15 pF | 1.2 | 3.0 | 5.1 | 1.2 | 5.6 | | |
| | | 3.0–3.6 | $R_L = 1 M\Omega$, $C_L = 15 pF$ | 0.8 | 2.2 | 3.4 | 0.8 | 3.8 | | |
| | | | $R_L = 500 \Omega,$ $C_L = 50 pF$ | 1.2 | 2.9 | 4.5 | 1.2 | 5.0 | | |
| | | 4.5–5.5 | $R_L = 1 M\Omega,$ $C_L = 15 pF$ | 0.5 | 1.8 | 2.8 | 0.5 | 3.1 | | |
| | | | $\begin{array}{l} R_{L} = 500 \ \Omega, \\ C_{L} = 50 \ pF \end{array}$ | 0.8 | 2.3 | 3.6 | 0.8 | 4.0 | | |
| C _{IN} | Input Capacitance | 5.5 | $V_{IN} = 0 V \text{ or } V_{CC}$ | | 2.5 | | | | pF | |
| C _{PD} | Power Dissipation Capacitance (Note 3) | 3.3 5.5 | $\begin{array}{c} 10 \text{ MHz} \\ \text{V}_{\text{IN}} = 0 \text{ V or } \text{V}_{\text{CC}} \end{array}$ | | 9 11 | | | | pF | |

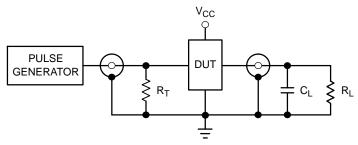
AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ nS}$)

3. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption: $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

NLX2G04







 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 4. Test Circuit

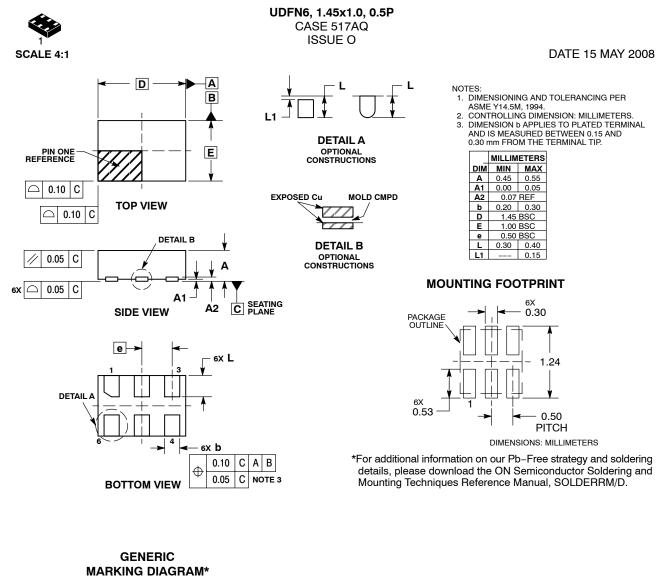
ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|--------------------------------------|-----------------------|
| NLX2G04BMX1TCG | ULLGA6, 1.2 x 1.0, 0.4P (Pb–Free) | 3000 / Tape & Reel |
| NLX2G04MUTCG | UDFN6, 1.2 x 1.0, 0.4P (Pb–Free) | 3000 / Tape & Reel |
| NLX2G04AMUTCG | UDFN6, 1.45 x 1.0, 0.5P (Pb–Free) | 3000 / Tape & Reel |
| NLX2G04CMUTCG | UDFN6, 1.0 x 1.0, 0.35P (Pb–Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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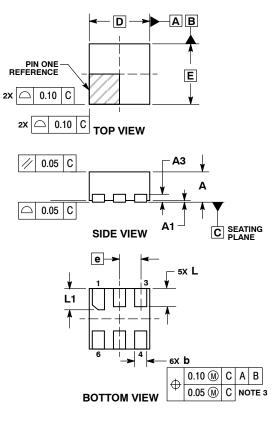
- X = Specific Device Code
- M = Date Code
- *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

| • | | | | | | | |
|---|--|--|--|--|--|--|--|
| PAGE 1 OF 1 | | | | | | | |
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SCALE 4:1



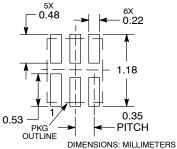
UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O**

DATE 18 MAY 2011

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN A DE ADD & OR MULTICAL TERMINAL TR
- AND 0.20 MM FROM TERMINAL TIP.
 PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

| BURRS AND MOLD FL | | | | | | | |
|-------------------|-------------|------|--|--|--|--|--|
| | MILLIMETERS | | | | | | |
| DIM | MIN MAX | | | | | | |
| Α | 0.45 0.55 | | | | | | |
| A1 | 0.00 0.05 | | | | | | |
| A3 | 0.13 | REF | | | | | |
| b | 0.12 0.22 | | | | | | |
| D | 1.00 | BSC | | | | | |
| Е | 1.00 BSC | | | | | | |
| е | 0.35 BSC | | | | | | |
| L | 0.25 0.35 | | | | | | |
| L1 | 0.30 | 0.40 | | | | | |

RECOMMENDED **SOLDERING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC **MARKING DIAGRAM***



X = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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ULLGA6, 1.2x1.0, 0.4P CASE 613AE-01 **ISSUE A** DATE 06 FEB 2008 SCALE 8:1 NOTES: D Α 1. DIMENSIONING AND TOLERANCING PER В ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. 2 CONTROLLING DIMENSION: MILLINGTERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP. A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE DACKAGE IS ALL OWED. 3. 4 PIN ONE REFERENCE Ε PACKAGE IS ALLOWED. MILLIMETERS DIM MIN MAX □ 0.10 C
 A
 --- 0.40

 A1
 0.00
 0.05

 b
 0.15
 0.25
 TOP VIEW □ 0.10 C D 1.20 BSC Εİ 1.00 BSC 0.40 BSC // 0.05 C el L 0.25 0.35 L1 0.35 0.45 Α SEATING PLANE 6X 🛆 0.05 C SIDE VIEW **MOUNTING FOOTPRINT** SOLDERMASK DEFINED* Ċ A1 5X 6X 0.49 0.26 е 5X L NOTE 4 N 1.24 L1 \mathbf{H} 0.53 0.40 6X b PITCH 0.10 C A B DIMENSIONS: MILLIMETERS Φ C NOTE 3 0.05 **BOTTOM VIEW**

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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